

N-Channel Power Trench[®] MOSFET 30 V, 16.9 A, 5.7 m Ω

Features

- Max $r_{DS(on)} = 5.7 \text{ m}\Omega$ at $V_{GS} = 10 \text{ V}$, $I_D = 16.9 \text{ A}$
- Max $r_{DS(on)}$ = 7.0 m Ω at V_{GS} = 4.5 V, I_D = 15.0 A
- High performance technology for extremely low r_{DS(on)}
- Termination is Lead-free and RoHS Compliant

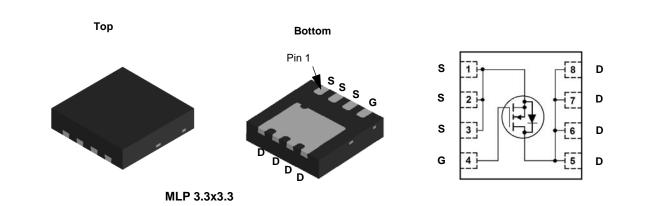


General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench[®] process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

Application

- DC DC Buck Converters
- Notebook battery power management
- Load switch in Notebook



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			30	V	
V _{GS}	Gate to Source Voltage			±20	V	
I _D	Drain Current -Continuous	T _C = 25 °C		20		
	-Continuous	T _A = 25 °C	(Note 1a)	16.9	Α	
	-Pulsed			50		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	144	mJ	
P _D	Power Dissipation $T_{C} = 25 \text{ °C}$			33	w	
	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	VV	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	
Thermal Ch	naracteristics					
$R_{\theta JC}$	Thermal Resistance, Junction to Case		3.7	°C/W		
R _{0.1A}	Thermal Resistance, Junction to Ambient		(Note 1a)	53		

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC7672	FDMC7672	MLP 3.3x3.3	13 "	12 mm	3000 units

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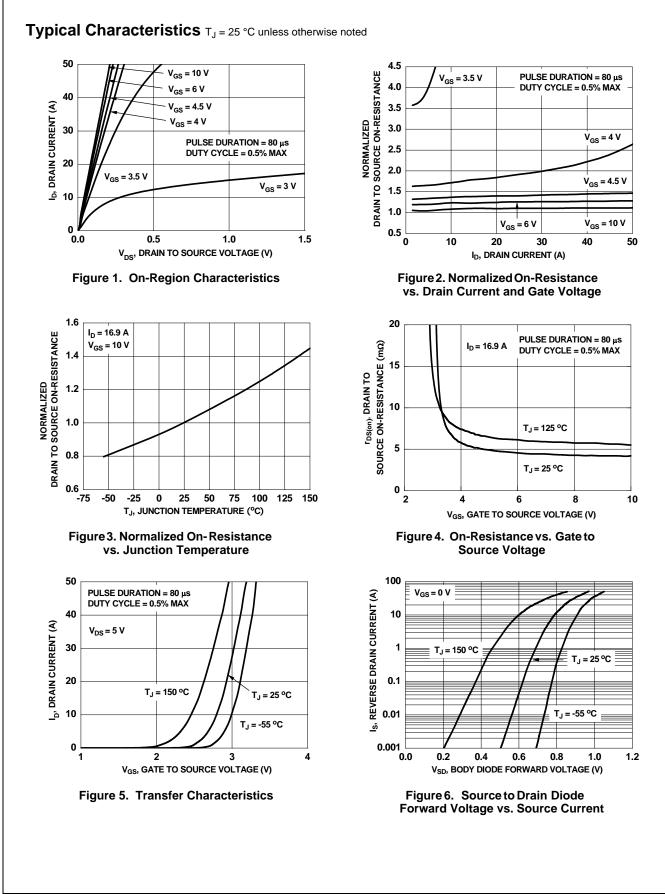
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \ \mu A, \ V_{GS} = 0 \ V$	30			V
ΔBV _{DSS} ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		13		mV/°C
-	Zara Cata Valtaga Drain Current	V _{DS} = 24 V, V _{GS} = 0 V			1	
DSS	Zero Gate Voltage Drain Current	T _J = 125 °C			250	- μΑ
I _{GSS}	Gate to Source Leakage Current	V _{GS} = 20 V, V _{DS} = 0 V			100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1.2	1.9	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-6		mV/°C
5		V _{GS} = 10 V, I _D = 16.9 A		4.3	5.7	
r _{DS(on)}	Statia Dania ta Causa On Desistanos	$V_{GS} = 4.5 \text{ V}, I_D = 15.0 \text{ A}$		5.4	7.0	
	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 16.9 \text{ A}$ T _J = 125 °C		5.5	6.9	- mΩ
9 _{FS}	Forward Transconductance	$V_{DD} = 5 \text{ V}, \ \text{I}_{D} = 16.9 \text{ A}$		82		S
	Characteristics				I	
C _{iss}	Input Capacitance			2925	3890	pF
C _{oss}	Output Capacitance	$V_{DS} = 15 V, V_{GS} = 0 V,$		1050	1400	pF
S _{rss}	Reverse Transfer Capacitance	f = 1 MHz		80	120	pF
Srss Rg	Gate Resistance			0.9	2.7	Ω
	y Characteristics			40		
t _{d(on)}	Turn-On Delay Time			13	24	ns
r	Rise Time	$V_{DD} = 15 \text{ V}, \text{ I}_{D} = 16.9 \text{ A},$		6	12	ns
d(off)	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		31	49	ns
f	Fall Time			5	10	ns
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		40	57	nC
	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V V_{DD} = 15 V$		18	24	nC
2 _{gs}	Total Gate Charge	I _D = 16.9 A		9		nC
Q _{gd}	Gate to Drain "Miller" Charge			4		nC
Drain-Soເ	urce Diode Characteristics					
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 16.9 A$ (Note 2)		0.83 1.2		V
SD	Source to Drain Diode 1 ofward voltage	$V_{GS} = 0 V, I_{S} = 1.9 A$ (Note 2)		0.72	1.2	•
rr	Reverse Recovery Time	I _F = 16.9 A, di/dt = 100 A/μs		39	62	ns
ວ _{rr}	Reverse Recovery Charge	·F ·····		18	32	nC

2: Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0 %. 3. E_{AS} of 144 mJ is based on starting T_J = 25 °C, L = 1 mH, I_{AS} = 17 A, V_{DD} = 27 V, V_{GS} = 10 V.

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

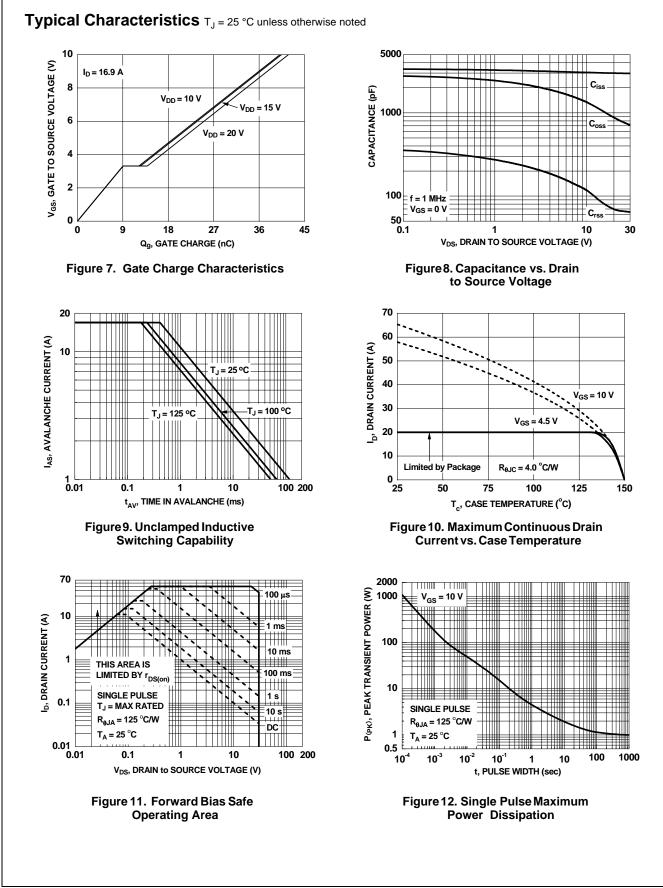
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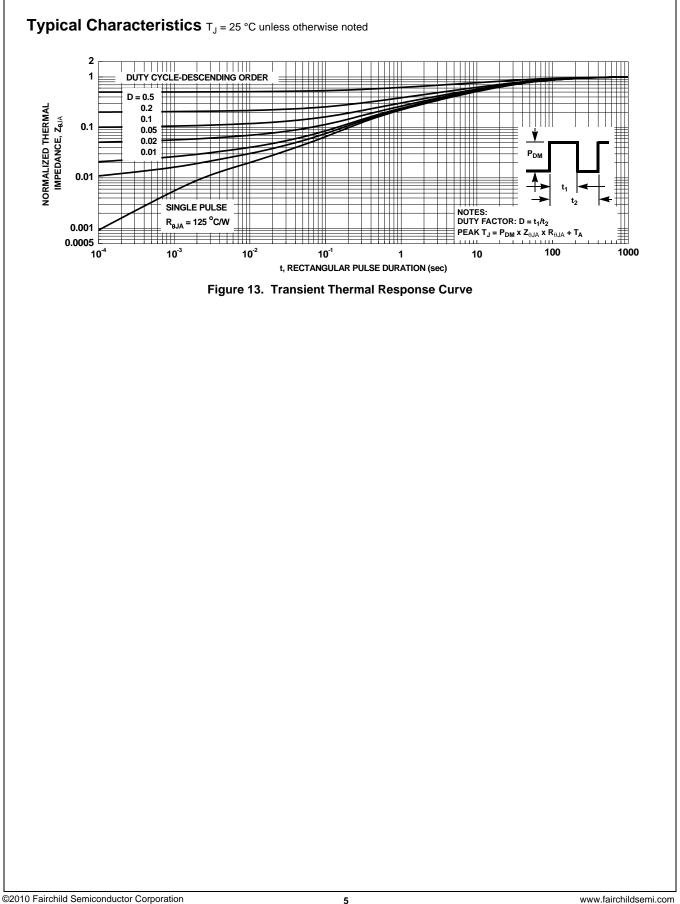


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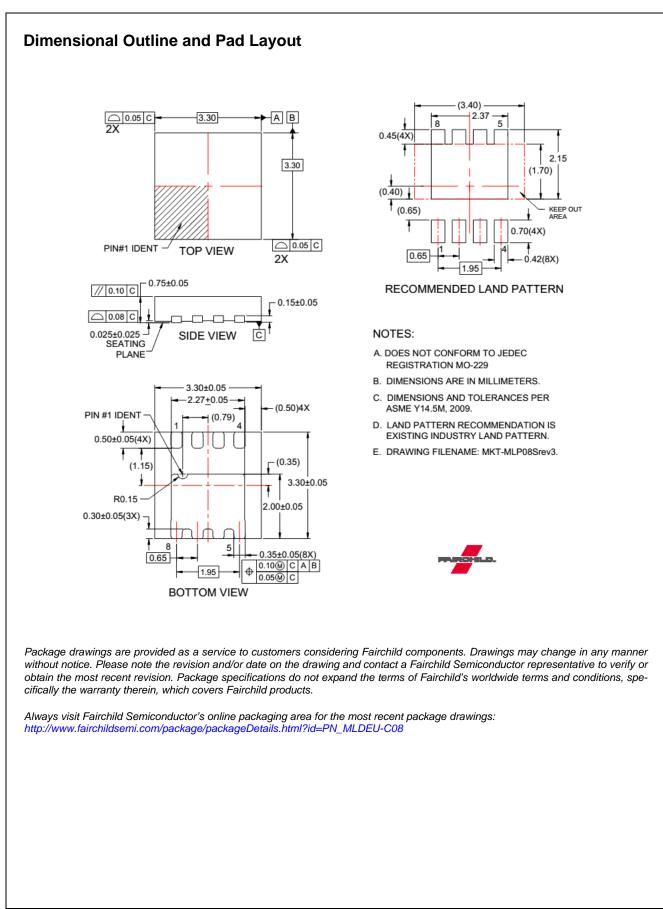


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